

BLD6G22L-50; BLD6G22LS-50

W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor

Rev. 4 — 1 September 2015

AMPLEON

Product data sheet

1. Product profile

1.1 General description

The BLD6G22L-50 and BLD22LS-50 incorporate a fully integrated Doherty solution using Ampleon's state of the art GEN6 LDMOS technology. This device is perfectly suited for CDMA base station applications at frequencies from 2110 MHz to 2170 MHz. The main and peak device, input splitter and output combiner are integrated in a single package. This package consists of one gate and drain lead and two extra leads of which one is used for biasing the peak amplifier and the other is not connected. It only requires the proper input/output match and bias setting as with a normal class-AB transistor.

Table 1. Typical performance

RF performance at $T_h = 25\text{ }^{\circ}\text{C}$.

Mode of operation	f (MHz)	V_{DS} (V)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	ACPR (dBc)	$P_{L(3dB)}$ (W)
W-CDMA [1][2]	2110 to 2170	28	8	14	40	-30	55

[1] Test signal: 2-carrier W-CDMA; test model 1; 64 DPCH; PAR = 8.3 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

[2] $I_{DQ} = 170\text{ mA}$ (main); $V_{GS(amp)peak} = 0\text{ V}$.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical W-CDMA performance at frequencies from 2110 MHz to 2170 MHz:
 - ◆ Average output power = 8 W
 - ◆ Power gain = 14 dB
 - ◆ Efficiency = 40 %
- Fully optimized integrated Doherty concept:
 - ◆ integrated asymmetrical power splitter at input
 - ◆ integrated power combiner
 - ◆ peak biasing down to 0 V
 - ◆ low junction temperature
 - ◆ high efficiency

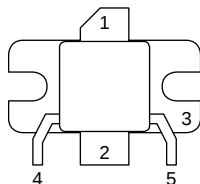
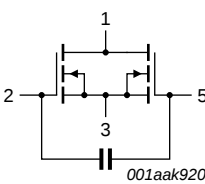
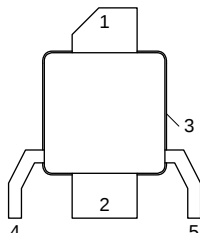
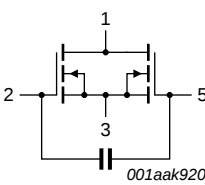
- 100 % peak power tested for guaranteed output power capability
- Integrated ESD protection
- Good pair match (main and peak on the same chip)
- Independent control of main and peak bias
- Internally matched for ease of use
- Excellent ruggedness
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- High efficiency RF power amplifiers with digital pre-distortion for W-CDMA multi carrier applications in the 2110 MHz to 2170 MHz range.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLD6G22L-50 (SOT1130A)			
1	drain		
2	gate + bias main		
3	source		
4	n.c.		
5	bias peak		
BLD6G22LS-50 (SOT1130B)			
1	drain		
2	gate + bias main		
3	source		
4	n.c.		
5	bias peak		

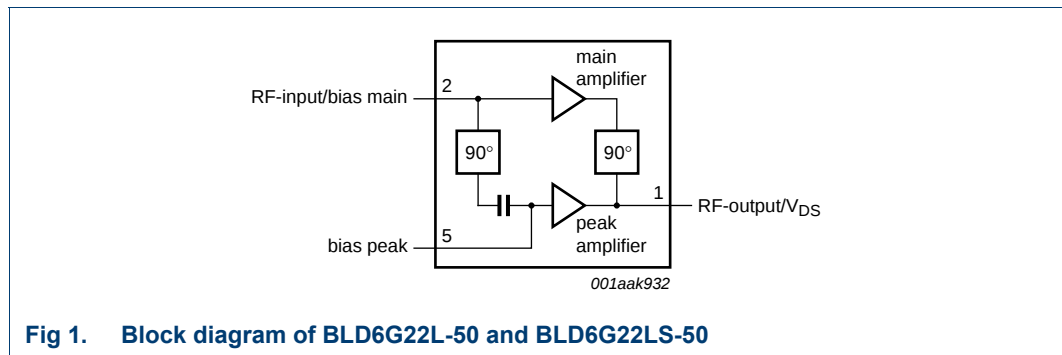
[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLD6G22L-50	-	flanged ceramic package; 2 mounting holes; 4 leads	SOT1130A
BLD6G22LS-50	-	earless flanged ceramic package; 4 leads	SOT1130B

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).
Valid for both main and peak device.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-0.5	+13	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-0.5	+13	V
I_D	drain current		-	10.2	A
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	200	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-case)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C}$; $P_L = 8\text{ W}$	[1] 1.9	K/W

[1] When operated with a 2-carrier (W-CDMA) modulated signal with PAR = 8.3 dB at 0.01 % probability on the CCDF.

7. Characteristics

Table 6. Characteristics

Valid for both main and peak device.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}$; $I_D = 0.62\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}$; $I_D = 31\text{ mA}$	1.4	1.8	2.4	V
V_{GSq}	gate-source quiescent voltage	$V_{DS} = 28\text{ V}$; $I_D = 170\text{ mA}$	1.55	2.05	2.55	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}$; $V_{DS} = 28\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$; $V_{DS} = 10\text{ V}$	4.95	5.5	-	A

Table 6. Characteristics ...continued
Valid for both main and peak device.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 1.55 \text{ A}$	1.4	2.2	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.085 \text{ A}$	-	0.52	0.736	Ω

8. Application information

Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 8.3 dB at 0.01 % probability on CCDF; carrier spacing = 5 MHz; $f = 2140 \text{ MHz}$; RF performance at $V_{DS} = 28 \text{ V}; I_{Dq} = 170 \text{ mA}; V_{GS(amp)peak} = 0 \text{ V}; T_{case} = 25 \text{ }^\circ\text{C}$; unless otherwise specified; in a production circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{L(AV)}$	average output power		-	8	-	W
G_p	power gain	$P_{L(AV)} = 8 \text{ W}$	12.5	14	-	dB
η_D	drain efficiency	$P_{L(AV)} = 8 \text{ W}$	37	40	-	%
PAR_O	output peak-to-average ratio	$P_{L(AV)} = 8 \text{ W}$	-	7.6	-	dB
RL_{in}	input return loss	$P_{L(AV)} = 8 \text{ W}$	10	17	-	dB
ACPR	adjacent channel power ratio	$P_{L(AV)} = 8 \text{ W}$	-	-30	-24	dBc

Table 8. Application information

Mode of operation: Pulsed CW; $\delta = 10 \text{ } \%$; $t_p = 100 \text{ } \mu\text{s}$; RF performance at $V_{DS} = 28 \text{ V}; I_{Dq} = 170 \text{ mA}; V_{GS(amp)peak} = 0 \text{ V}; T_{case} = 25 \text{ }^\circ\text{C}$; unless otherwise specified; in a production circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{L(3dB)}$	output power at 3 dB gain compression		46	55	-	W

8.1 Ruggedness in Doherty operation

The BLD6G22L-50 and BLD6G22LS-50 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}; I_{Dq} = 170 \text{ mA}; P_L = 8 \text{ W}$ (W-CDMA); $f = 2140 \text{ MHz}$.

8.2 Impedance information

Table 9. Typical impedance

Measured load-pull data; typical values unless otherwise specified.

f MHz	Z_S Ω	Z_L Ω
2050	9.4 – 12.3j	5.5 – 7.6j
2110	11.4 – 11.2j	6.7 – 8.2j
2140	12.3 – 10.5j	7.0 – 7.5j
2170	12.2 – 9.3j	7.2 – 6.8j
2230	11.8 – 7.3j	5.4 – 5.5j

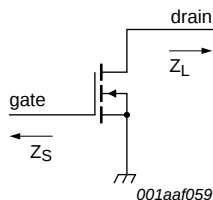
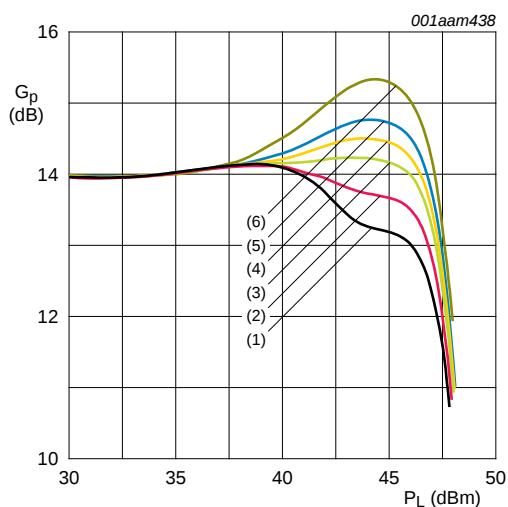


Fig 2. Definition of transistor impedance

8.3 Performance curves

Performance curves are measured in a BLD6G22L-50 application circuit.

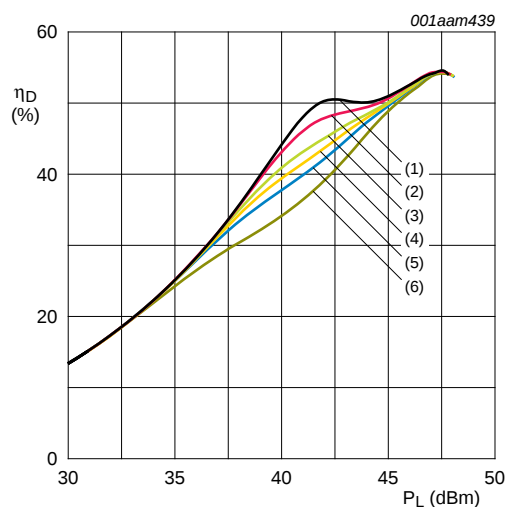
8.3.1 CW pulsed



$V_{DS} = 28 \text{ V}$; $I_{DQ} = 170 \text{ mA}$ (main); $T_{case} = 25 \text{ }^{\circ}\text{C}$;
 $f = 2140 \text{ MHz}$; $\delta = 10 \%$; $t_p = 100 \text{ } \mu\text{s}$ on 1 ms period.

- (1) $V_{GS(amp)peak} = 0 \text{ V}$
- (2) $V_{GS(amp)peak} = 0.2 \text{ V}$
- (3) $V_{GS(amp)peak} = 0.4 \text{ V}$
- (4) $V_{GS(amp)peak} = 0.5 \text{ V}$
- (5) $V_{GS(amp)peak} = 0.6 \text{ V}$
- (6) $V_{GS(amp)peak} = 0.8 \text{ V}$

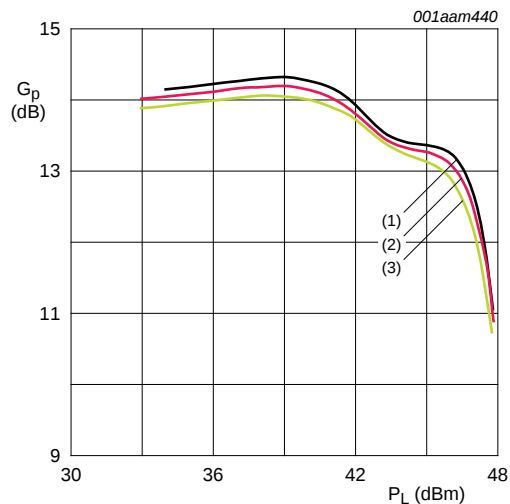
Fig 3. Power gain as a function of load power; typical values



$V_{DS} = 28 \text{ V}$; $I_{DQ} = 170 \text{ mA}$ (main); $T_{case} = 25 \text{ }^{\circ}\text{C}$;
 $f = 2140 \text{ MHz}$; $\delta = 10 \%$; $t_p = 100 \text{ } \mu\text{s}$ on 1 ms period.

- (1) $V_{GS(amp)peak} = 0 \text{ V}$
- (2) $V_{GS(amp)peak} = 0.2 \text{ V}$
- (3) $V_{GS(amp)peak} = 0.4 \text{ V}$
- (4) $V_{GS(amp)peak} = 0.5 \text{ V}$
- (5) $V_{GS(amp)peak} = 0.6 \text{ V}$
- (6) $V_{GS(amp)peak} = 0.8 \text{ V}$

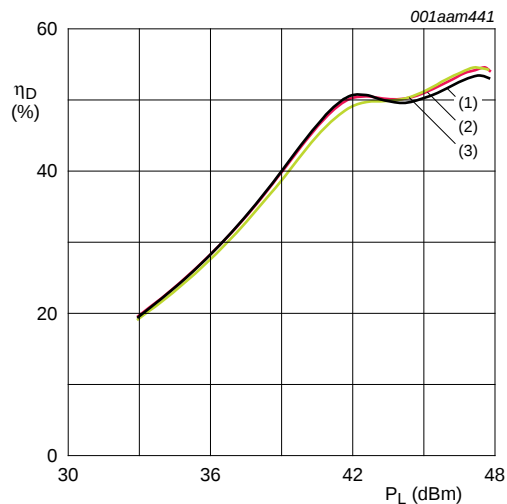
Fig 4. Drain efficiency as a function of load power; typical values



$V_{DS} = 28$ V; $I_{DQ} = 170$ mA (main); $T_{case} = 25$ °C;
 $V_{GS(amp)peak} = 0$ V; $\delta = 10$ %; $t_p = 100$ μ s on 1 ms period.

- (1) $f = 2110$ MHz
- (2) $f = 2140$ MHz
- (3) $f = 2170$ MHz

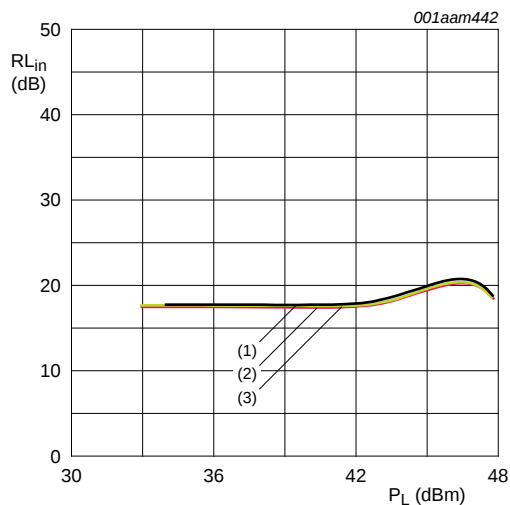
Fig 5. Power gain as a function of load power; typical values



$V_{DS} = 28$ V; $I_{DQ} = 170$ mA (main); $T_{case} = 25$ °C;
 $V_{GS(amp)peak} = 0$ V; $\delta = 10$ %; $t_p = 100$ μ s on 1 ms period.

- (1) $f = 2110$ MHz
- (2) $f = 2140$ MHz
- (3) $f = 2170$ MHz

Fig 6. Drain efficiency as a function of load power; typical values

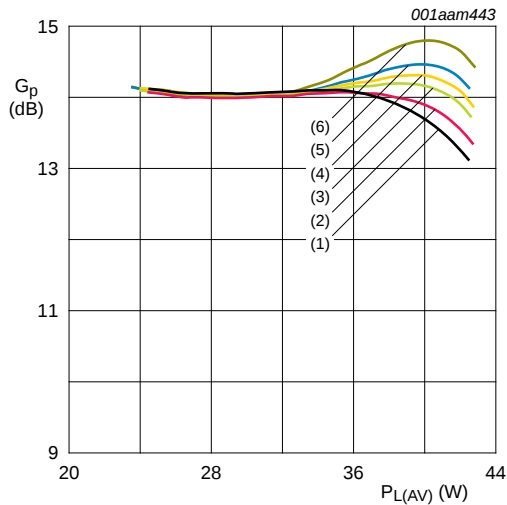


$V_{DS} = 28$ V; $I_{DQ} = 170$ mA (main); $T_{case} = 25$ °C; $V_{GS(amp)peak} = 0$ V; $\delta = 10$ %; $t_p = 100$ μ s on 1 ms period.

- (1) $f = 2110$ MHz
- (2) $f = 2140$ MHz
- (3) $f = 2170$ MHz

Fig 7. Input return loss as a function of load power; typical values

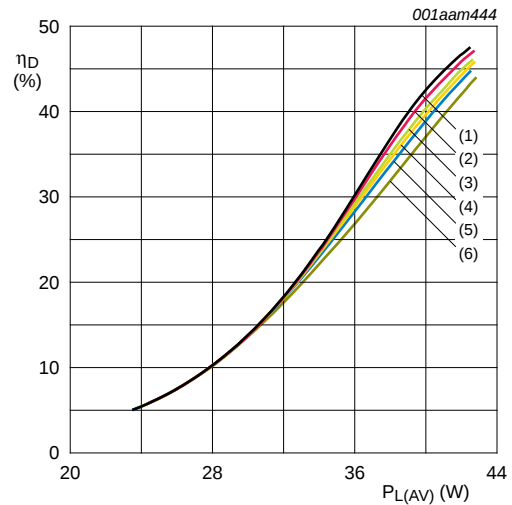
8.3.2 W-CDMA



$V_{DS} = 28 \text{ V}$; $I_{DQ} = 170 \text{ mA}$ (main); $T_{case} = 25 \text{ }^{\circ}\text{C}$;
 $f = 2140 \text{ MHz}$; 2-carrier W-CDMA; PAR = 8.3 dB at
 0.01 % probability on CCDF.

- (1) $V_{GS(amp)peak} = 0 \text{ V}$
- (2) $V_{GS(amp)peak} = 0.2 \text{ V}$
- (3) $V_{GS(amp)peak} = 0.4 \text{ V}$
- (4) $V_{GS(amp)peak} = 0.5 \text{ V}$
- (5) $V_{GS(amp)peak} = 0.6 \text{ V}$
- (6) $V_{GS(amp)peak} = 0.8 \text{ V}$

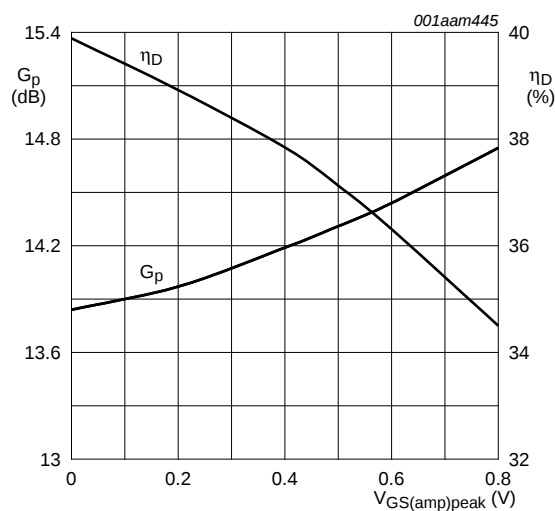
Fig 8. Power gain as a function of average load power; typical values



$V_{DS} = 28 \text{ V}$; $I_{DQ} = 170 \text{ mA}$ (main); $T_{case} = 25 \text{ }^{\circ}\text{C}$;
 $f = 2140 \text{ MHz}$; 2-carrier W-CDMA; PAR = 8.3 dB at
 0.01 % probability on CCDF.

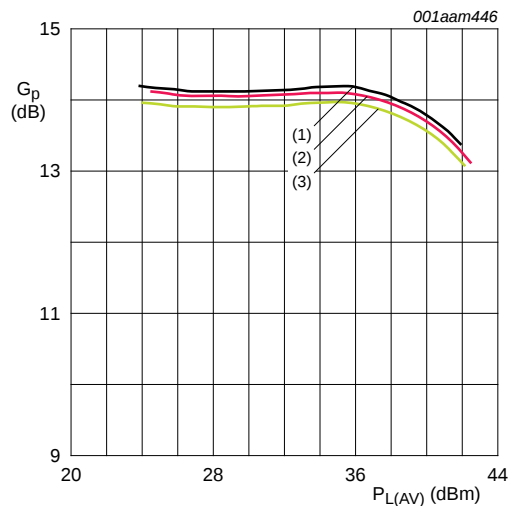
- (1) $V_{GS(amp)peak} = 0 \text{ V}$
- (2) $V_{GS(amp)peak} = 0.2 \text{ V}$
- (3) $V_{GS(amp)peak} = 0.4 \text{ V}$
- (4) $V_{GS(amp)peak} = 0.5 \text{ V}$
- (5) $V_{GS(amp)peak} = 0.6 \text{ V}$
- (6) $V_{GS(amp)peak} = 0.8 \text{ V}$

Fig 9. Drain efficiency as a function of average load power; typical values



$V_{DS} = 28 \text{ V}$; $I_{DQ} = 170 \text{ mA}$ (main); $T_{case} = 25 \text{ }^{\circ}\text{C}$; $f = 2140 \text{ MHz}$; 2-carrier W-CDMA; PAR = 8.3 dB
 at 0.01 % probability on CCDF.

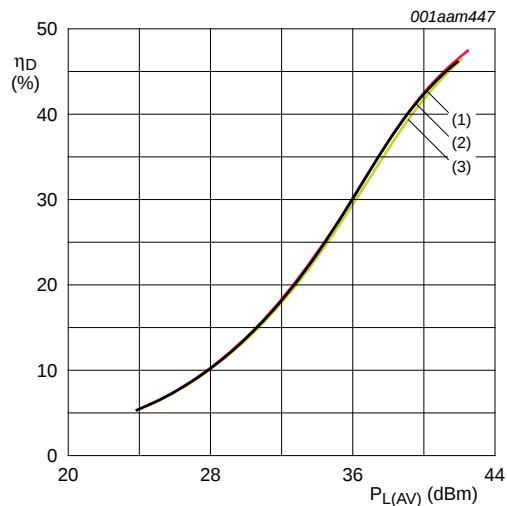
Fig 10. Power gain and drain efficiency as function of load power; typical values



$V_{DS} = 28$ V; $I_{Dq} = 170$ mA (main); $T_{case} = 25$ °C;
 $V_{GS(amp)peak} = 0$ V; 2-carrier W-CDMA; PAR = 8.3 dB at
 0.01 % probability on CCDF.

- (1) $f = 2110$ MHz
- (2) $f = 2140$ MHz
- (3) $f = 2170$ MHz

Fig 11. Power gain as a function of average load power; typical values



$V_{DS} = 28$ V; $I_{Dq} = 170$ mA (main); $T_{case} = 25$ °C;
 $V_{GS(amp)peak} = 0$ V; 2-carrier W-CDMA; PAR = 8.3 dB at
 0.01 % probability on CCDF.

- (1) $f = 2110$ MHz
- (2) $f = 2140$ MHz
- (3) $f = 2170$ MHz

Fig 12. Drain efficiency as a function of average load power; typical values

9. Test information

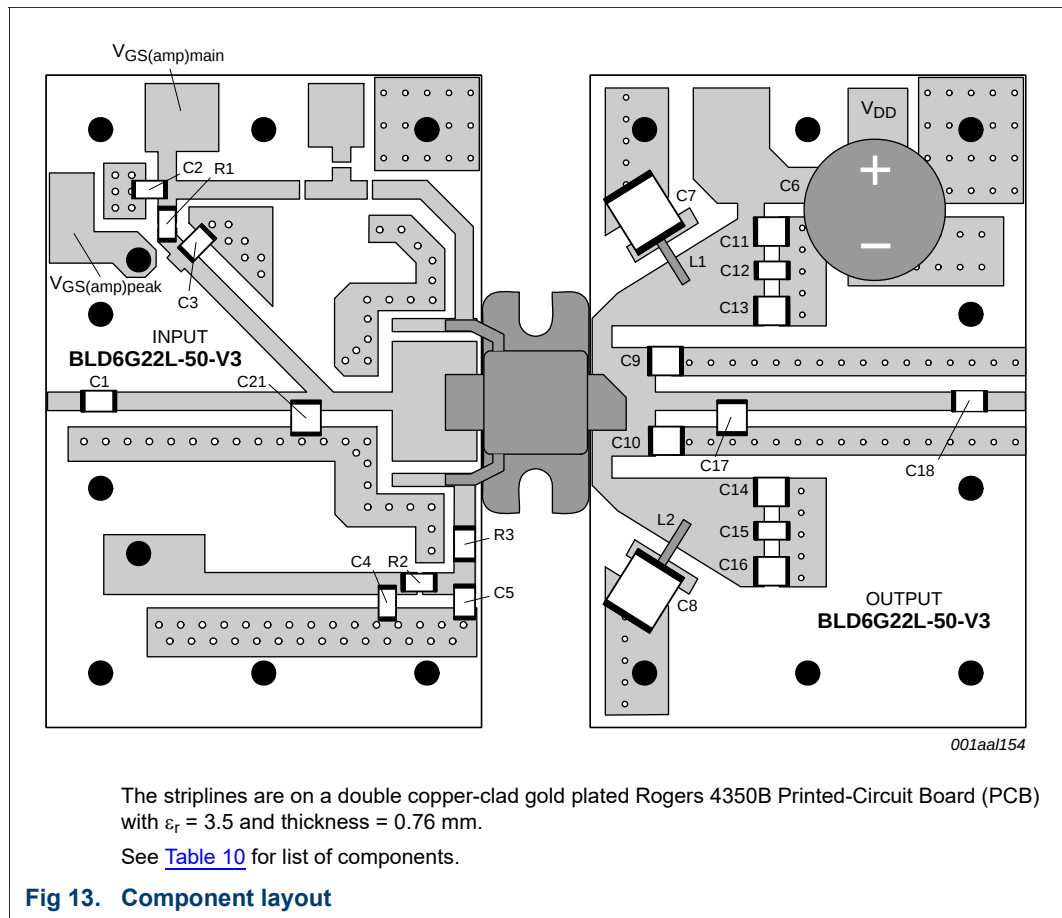


Table 10. List of components

See [Figure 13](#) for component layout.

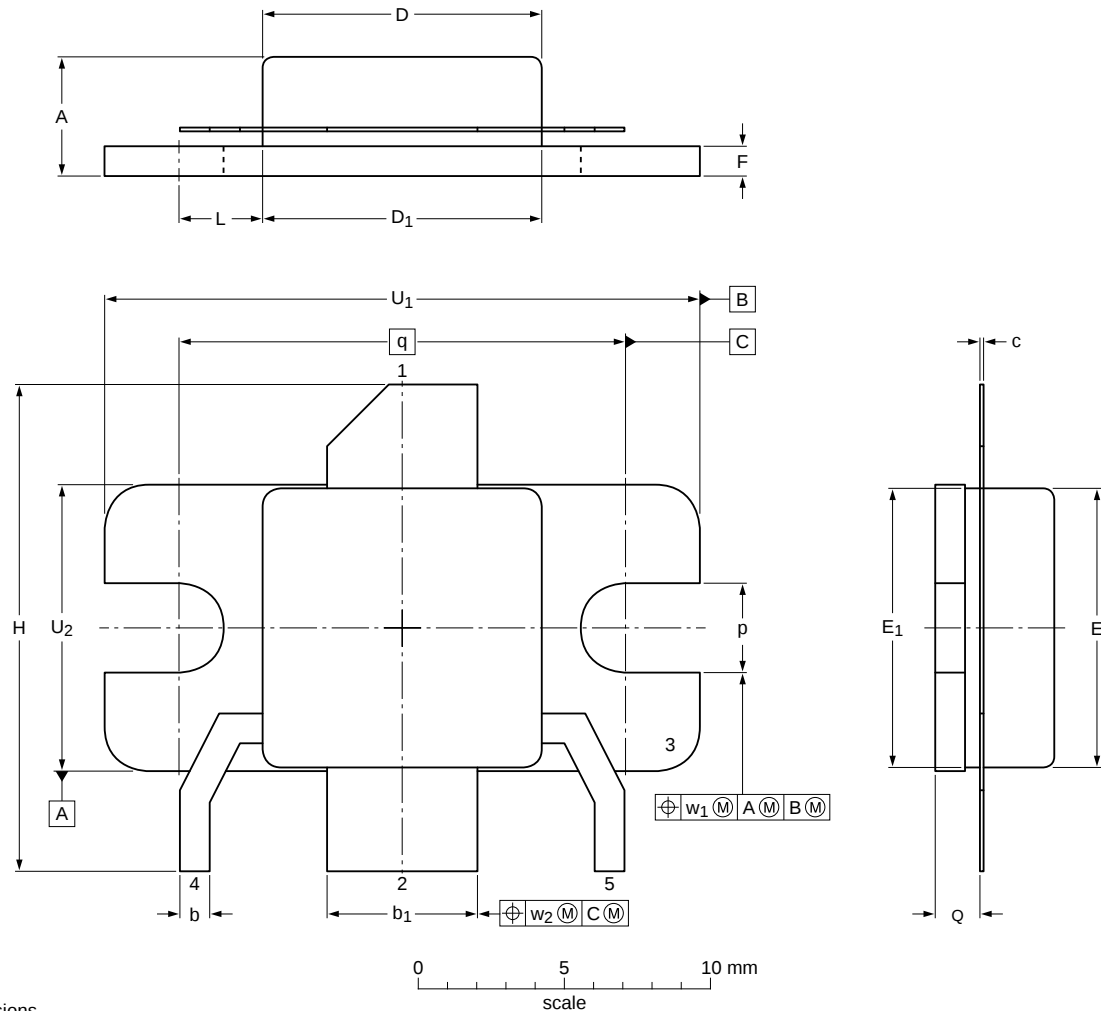
Component	Description	Value	Dimensions
C1, C3, C5, C18	multilayer ceramic chip capacitor	9.1 pF	[1]
C2, C4, C12, C15	multilayer ceramic chip capacitor	100 nF	
C6	electrolytic capacitor	470 μ F; 63 V	
C7, C8	multilayer ceramic chip capacitor	10 μ F	
C9, C10	multilayer ceramic chip capacitor	1.2 pF	[1]
C11, C13, C14, C16	multilayer ceramic chip capacitor	8.2 pF	[1]
C17	multilayer ceramic chip capacitor	0.8 pF	[1]
C21	multilayer ceramic chip capacitor	1.0 pF	[1]
L1, L2	copper wire	-	diameter = 0.8 mm; length = 8 mm
R1	SMD resistor	3.6 Ω	1206
R2	SMD resistor	33 Ω	1206
R3	SMD resistor	10 Ω	1206

[1] American Technical Ceramics type 100B or capacitor of same quality.

10. Package outline

Flanged ceramic package; 2 mounting holes; 4 leads

SOT1130A



Dimensions

Unit ⁽¹⁾	A	b	b ₁	c	D	D ₁	E	E ₁	F	H	L	p	Q ⁽²⁾	q	U ₁	U ₂	w ₁	w ₂
mm	max	4.65	1.14	5.26	0.18	9.65	9.65	9.65	9.65	1.14	17.12	3.00	3.30	1.70	20.45	9.91		
	nom													15.24			0.25	0.51
	min	3.76	0.89	5.00	0.10	9.40	9.40	9.40	9.40	0.89	16.10	2.69	2.92	1.45	20.19	9.65		
inches	max	0.183	0.045	0.207	0.007	0.38	0.38	0.38	0.38	0.045	0.674	0.118	0.130	0.067	0.805	0.39		
	nom													0.6			0.01	0.02
	min	0.148	0.035	0.197	0.004	0.37	0.37	0.37	0.37	0.035	0.634	0.106	0.115	0.057	0.795	0.38		

Note

1. millimeter dimensions are derived from the original inch dimensions.

2. dimension is measured 0.030 inch (0.76 mm) from the body.

sot1130a_po

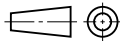
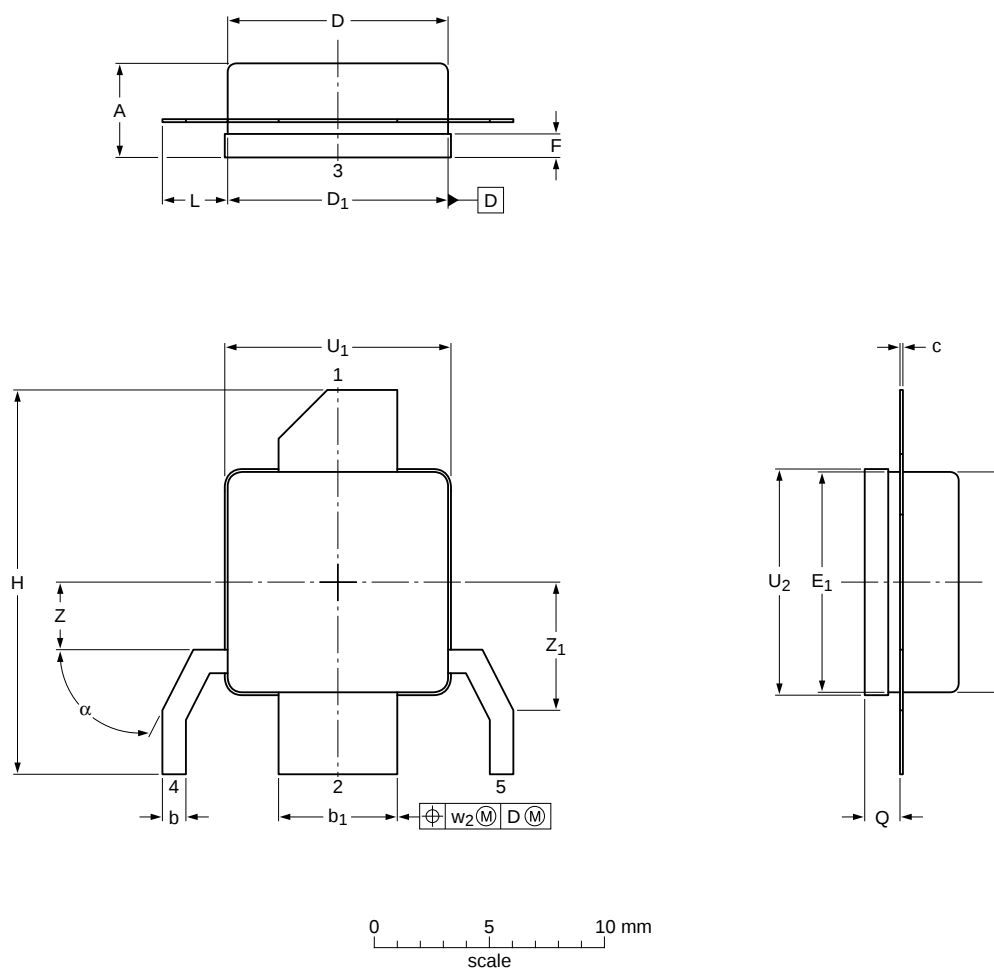
Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1130A						09-10-12 10-02-02

Fig 14. Package outline SOT1130A

Earless flanged ceramic package; 4 leads

SOT1130B



Dimensions

Unit ⁽¹⁾	A	b	b ₁	c	D	D ₁	E	E ₁	F	H	L	Q	U ₁	U ₂	w ₂	Z	Z ₁	α
mm	max	4.65	1.14	5.26	0.18	9.65	9.65	9.65	1.14	17.12	3.00	1.70	9.91	9.91		3.05	5.66	64°
	nom														0.51			
	min	3.76	0.89	5.00	0.10	9.40	9.40	9.40	0.89	16.10	2.69	1.45	9.65	9.65		2.79	5.41	62°
inches	max	0.183	0.045	0.207	0.007	0.38	0.38	0.38	0.045	0.674	0.118	0.069	0.39	0.39		0.120	0.223	64°
	nom														0.02			
	min	0.148	0.035	0.197	0.004	0.37	0.37	0.37	0.035	0.634	0.106	0.059	0.38	0.38		0.110	0.213	62°

Note

1. millimeter dimensions are derived from the original inch dimensions.

2. dimension is measured 0.030 inch (0.76 mm) from the body.

sot1130b_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1130B						09-10-12 09-12-14

Fig 15. Package outline SOT1130B

11. Abbreviations

Table 11. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
CDMA	Code Division Multiple Access
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLD6G22L-50_BLD6G22LS-50#4	20150901	Product data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.3
Modifications:	- The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. - Legal texts have been adapted to the new company name where appropriate.			
BLD6G22L-50_BLD6G22LS-50 v.3	20100817	Product data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.2
BLD6G22L-50_BLD6G22LS-50 v.2	20100318	Objective data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.1
BLD6G22L-50_BLD6G22LS-50 v.1	20091215	Objective data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

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14. Contact information

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